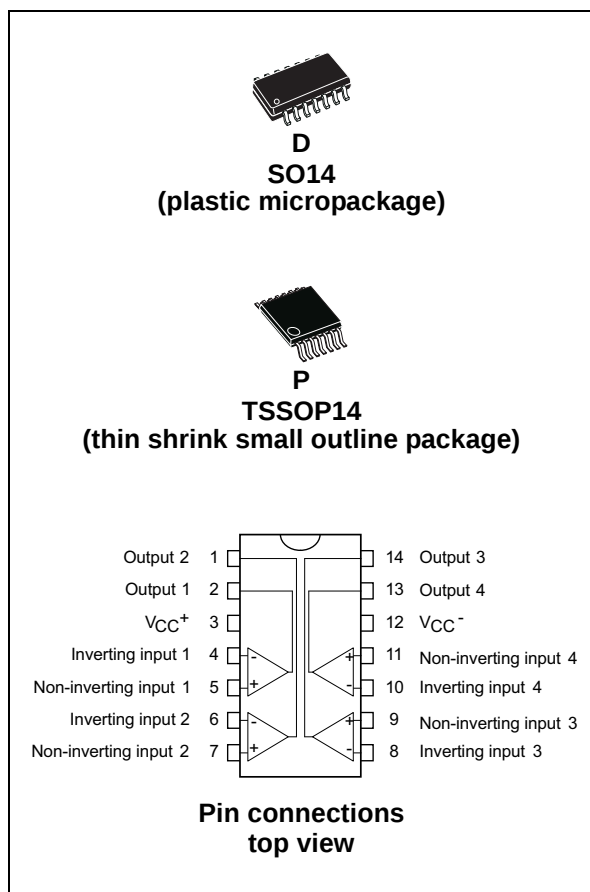


Micropower quad CMOS voltage comparator

Datasheet - production data



Features

- Extremely low supply current: 9 μ A typ./comparator
- Wide single supply range 2.7 V to 16 V or dual supplies (± 1.35 V to ± 8 V)
- Extremely low input bias current: 1 pA typ.
- Extremely low input offset current: 1 pA typ.
- Input common-mode voltage range includes GND
- High input impedance: $10^{12} \Omega$ typ.
- Fast response time: 1.5 μ s typ. for 5 mV overdrive
- Pin-to-pin and functionally compatible with bipolar LM339 device

Description

The TS339 device is a micro-power, CMOS, quad voltage comparator with extremely low consumption of 9 μ A typ./comparator (20 times less than the bipolar LM339). Similar performances are offered by the quad micro-power comparator TS3704 with a push-pull CMOS output. Thus response times remain similar to the LM339 device.

Table 1. Device summary

Order code	Temperature range	Package	Packaging	Marking
TS339CDT	0 °C, 70 °C	SO14	Tape and reel	S339C
TS339CPT		TSSOP14		
TS339IDT	-40 °C, 125 °C	SO14		S339I
TS339IPT		TSSOP14		

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1 Absolute maximum ratings

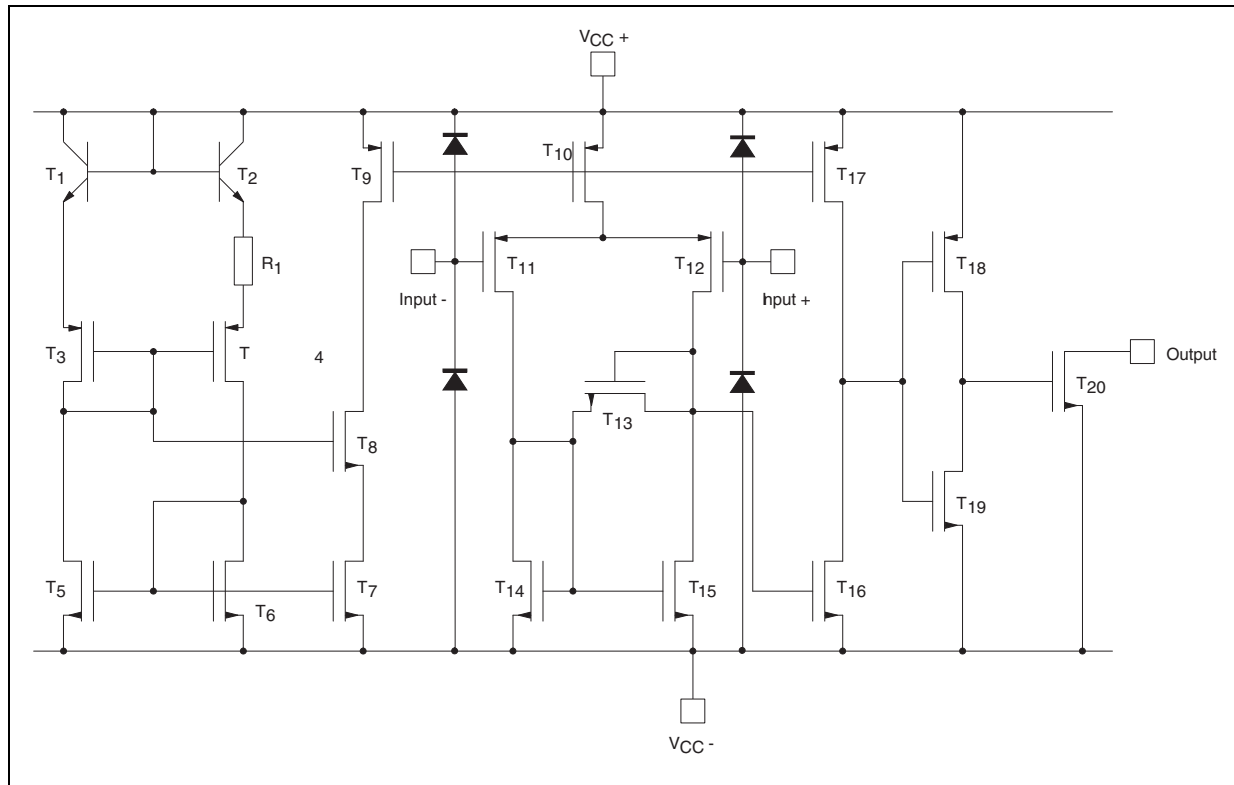
Table 2. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}^{+}	Supply voltage ⁽¹⁾	18	V
V_{id}	Differential input voltage ⁽²⁾	±18	
V_i	Input voltage ⁽³⁾	18	
V_o	Output voltage	18	
I_o	Output current	20	mA
I_F	Forward current in ESD protection diodes on inputs ⁽⁴⁾	50	
p_d	Power dissipation ⁽⁵⁾ SO14 TSSOP14	830 710	mW
T_{stg}	Storage temperature range	-65 to +150	°C
ESD	HBM: human body model ⁽⁶⁾	50	V
	MM: machine model ⁽⁷⁾	40	
	CDM: charged device model	800	

1. All voltage values, except the differential voltage, are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. Excursions of input voltages may exceed the power supply level. As long as the common mode voltage $[V_{icm}=(V_{in}^{+} + V_{in}^{-})/2]$ remains within the specified range, the comparator will provide a stable output state. However, the maximum current through the ESD diodes (I_F) of the input stage must strictly be observed.
4. Guaranteed by design.
5. p_d is calculated with $T_{amb} = +25\text{ °C}$, $T_j = +150\text{ °C}$ and
 $R_{thja} = 150\text{ °C/W}$ for SO14 package
 $R_{thja} = 175\text{ °C/W}$ for TSSOP14 package.
6. Human body model, 100pF discharged through a 1.5 kΩ resistor into pin of device.
7. Machine model ESD, a 200 pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5 Ω), into pin to pin of device.

2 Typical application schematics

Figure 1. Schematic diagram (for 1/4 TS339)



3 Electrical characteristics

Table 3. $V_{CC}^+ = 3\text{ V}$, $V_{CC}^- = 0\text{ V}$, $T_{amb} = 25\text{ °C}$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage ⁽¹⁾ $V_{ic} = 1.5\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$.			5 6.5	mV
I_{io}	Input offset current ⁽²⁾ $V_{ic} = 1.5\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$.		1	300	pA
I_{ib}	Input bias current ⁽²⁾ $V_{ic} = 1.5\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$.		1	600	
V_{icm}	Input common mode voltage range $T_{min} \leq T_{amb} \leq T_{max}$	0 0		$V_{CC}^+ - 1.2$ $V_{CC}^+ - 1.5$	V
CMR	Common-mode rejection ratio $V_{ic} = V_{icm\ min}$.		70		dB
SVR	Supply voltage rejection ratio $V_{CC}^+ = 3\text{ V to }5\text{ V}$		70		
I_{OH}	High level output current $V_{id} = +1\text{ V}$, $V_{OH} = 3\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$.		2	40 1000	nA
V_{OL}	Low level output voltage $V_{id} = -1\text{ V}$, $I_{OL} = +6\text{ mA}$ $T_{min} \leq T_{amb} \leq T_{max}$.		400	550 800	mV
I_{CC}	Supply current (each comparator) No load - outputs low $T_{min} \leq T_{amb} \leq T_{max}$.		9	20 25	μA
t_{PLH}	Response time low to high $V_{ic} = 0\text{ V}$, $f = 10\text{ kHz}$, $T_{min} \leq T_{amb} \leq T_{max}$, $C_L = 50\text{ pF}$, overdrive = 5 mV TTL input		1.5 0.7		μs
t_{PHL}	Response time high to low $V_{ic} = 0\text{ V}$, $f = 10\text{ kHz}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$, overdrive = 5 mV TTL input		2.5 0.08		

1. The specified offset voltage is the maximum value required to drive the output up to 2.5 V or down to 0.3 V.
2. Maximum values including unavoidable inaccuracies of the industrial test.

Table 4. $V_{CC}^+ = 5\text{ V}$, $V_{CC}^- = 0\text{ V}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage ⁽¹⁾ $V_{ic} = 2.5\text{ V}$, $V_{CC}^+ = 5\text{ V}$ to 10 V $T_{min.} \leq T_{amb} \leq T_{max.}$		1.4	5 6.5	mV
I_{io}	Input offset current ⁽²⁾ $V_{ic} = 2.5\text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	300	pA
I_{ib}	Input bias current ⁽²⁾ $V_{ic} = 2.5\text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	600	
V_{icm}	Input common mode voltage range $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC}^+ - 1.2$ $V_{CC}^+ - 1.5$	V
CMR	Common-mode rejection ratio $V_{ic} = 0\text{ V}$		75		dB
SVR	Supply voltage rejection ratio $V_{CC}^+ = +5\text{ V}$ to $+10\text{ V}$		85		
I_{OH}	High level output voltage $V_{id} = 1\text{ V}$, $V_{OH} = +5\text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		27	40 1000	nA
V_{OL}	Low level output voltage $V_{id} = -1\text{ V}$, $I_{OL} = 6\text{ mA}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		260	400 650	mV
I_{CC}	Supply current (each comparator) No load - outputs low $T_{min.} \leq T_{amb} \leq T_{max.}$		10	20 25	μA
t_{PLH}	Response time low to high $V_{ic} = 0\text{ V}$, $f = 10\text{ kHz}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 15\text{ pF}$, overdrive = 5 mV Overdrive = 10 mV Overdrive = 20 mV Overdrive = 40 mV TTL input		1.5 1.2 1.1 0.9 0.8		μs
t_{PHL}	Response time high to low $V_{ic} = 0\text{ V}$, $f = 10\text{ kHz}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 15\text{ pF}$, overdrive = 5 mV Overdrive = 10 mV Overdrive = 20 mV Overdrive = 40 mV TTL input		2.5 1.9 1.2 0.8 0.08		
t_f	Fall time $f = 10\text{ kHz}$, $C_L = 50\text{ pF}$, $R_L = 5.1\text{ k}\Omega$, overdrive 50 mV		30		ns

1. The specified offset voltage is the maximum value required to drive the output up to 4.5 V or down to 0.3 V .

2. Maximum values including unavoidable inaccuracies of the industrial test.

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

4.1 SO14 package information

Figure 2. SO14 package outline

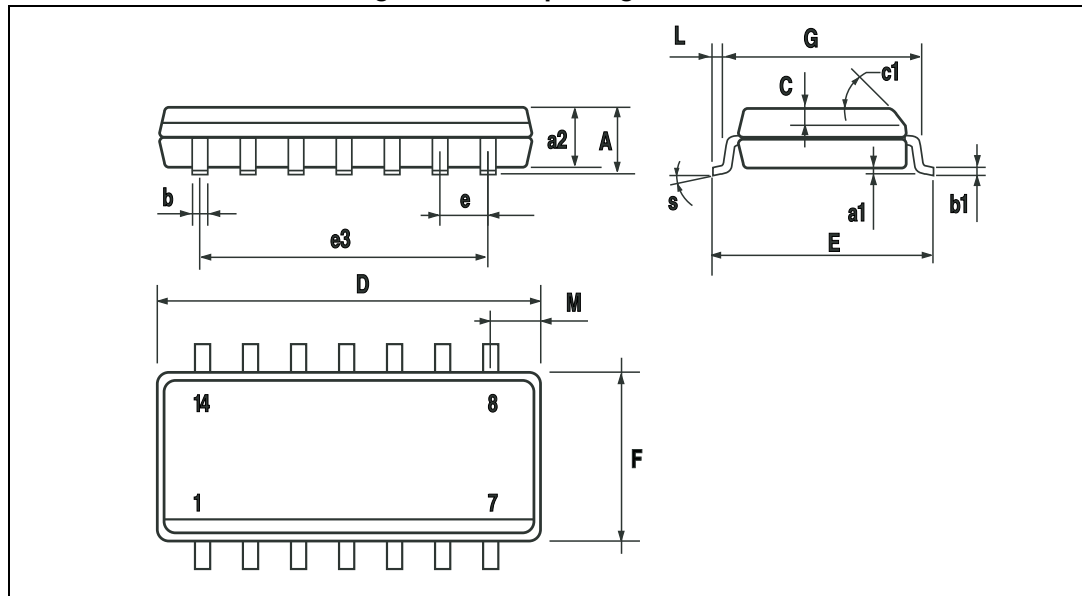


Table 5. SO14 package mechanical data

Symbol	Dimensions					
	mm			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					

4.2 TSSOP14 package information

Figure 3. TSSOP14 package outline

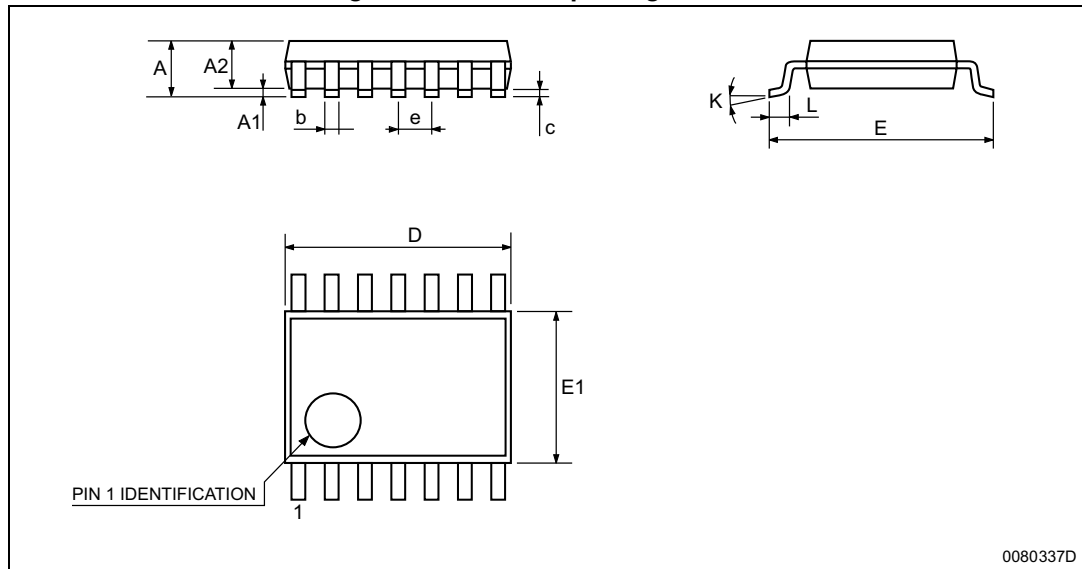


Table 6. TSSOP14 package mechanical data

Symbol	Dimensions					
	mm.			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

5 Revision history

Table 7. Document revision history

Date	Revision	Changes
Jan. 2003	1	Initial release.
Aug. 2005	2	1 - PPAP references inserted in the datasheet see <i>Table 1: Order codes on page 1</i> . 2 - ESD protection inserted in <i>Table 2 Key parameters and their absolute maximum ratings on page 2</i> .
04-Sep-2012	3	Updated <i>Features, Table 1</i> , removed TS339IYD and TS339IYDT from <i>Table 1</i> . Updated ECOPACK text, reformatted <i>Section 4: Package information</i> . Minor corrections throughout document.
21-Feb-2014	4	Removed DIP package <i>Features</i> : updated fast response time <i>Device summary</i> : removed order codes TS339CN, TS339IN, and TS339ID; added temperature range for order codes TS339IDT and TS339IPT
16-Mar-2021	5	Updated the device summary table in cover page.

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